

# 7MBR10VKA060-50

**IGBT Modules**

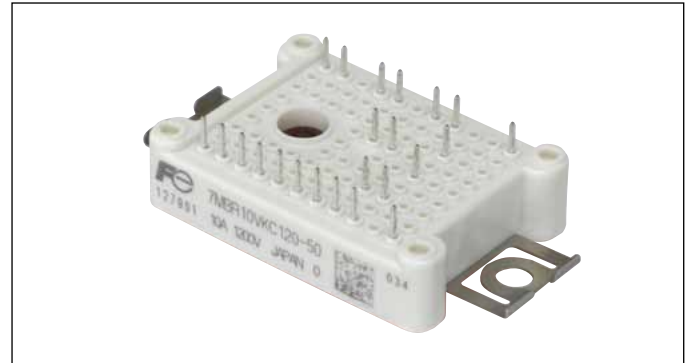
## IGBT MODULE (V series) 600V / 10A / PIM

### ■ Features

- Low  $V_{CE(sat)}$
- Compact Package
- P.C.Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit
- RoHS compliant product

### ■ Applications

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterruptible Power Supply



### ■ Maximum Ratings and Characteristics

#### ● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

| Items   | Symbols   | Conditions      | Maximum ratings                    | Units            |                      |
|---|---|-----------------|------------------------------------|------------------|----------------------|
| Inverter  | Collector-Emitter voltage   | $V_{CES}$       | 600                                | V                |                      |
|   | Gate-Emitter voltage  | $V_{GES}$       | $\pm 20$                           | V                |                      |
|   | Collector current   | $I_c$           | Continuous $T_c=100^\circ\text{C}$ | 10               | A                    |
|   |   | $I_{cp}$        | 1ms $T_c=80^\circ\text{C}$         | 20               |                      |
|   |   | $-I_c$          |                                    | 10               |                      |
|   | $-I_{c\ pulse}$   | 1ms             | 20                                 |                  |                      |
| Collector power dissipation                                 | $P_c$   | 1 device        | 70                                 | W                |                      |
| Brake   | Collector-Emitter voltage   | $V_{CES}$       | 600                                | V                |                      |
|   | Gate-Emitter voltage  | $V_{GES}$       | $\pm 20$                           | V                |                      |
|   | Collector current   | $I_c$           | Continuous $T_c=80^\circ\text{C}$  | 10               | A                    |
|   |   | $I_{cp}$        | 1ms $T_c=80^\circ\text{C}$         | 20               |                      |
|   | Collector power dissipation   | $P_c$           | 1 device                           | 70               | W                    |
| Repetitive peak reverse voltage (Diode)                     | $V_{RRM}$   |                 | 600                                | V                |                      |
| Converter   | Repetitive peak reverse voltage   | $V_{RRM}$       | 800                                | V                |                      |
|   | Average output current  | $I_o$           | 50Hz/60Hz, sine wave               | 10               | A                    |
|   | Surge current (Non-Repetitive)  | $I_{FSM}$       | 10ms, $T_j=150^\circ\text{C}$      | 360              | A                    |
|   | $I^2t$ (Non-Repetitive)   | $I^2t$          | half sine wave                     | 660              | $\text{A}^2\text{s}$ |
| Junction temperature  | $T_j$   | Inverter, Brake | 175                                | $^\circ\text{C}$ |                      |
|   |   | Converter       | 150                                |                  |                      |
| Operating junction temperature (under switching conditions) | $T_{jop}$   | Inverter, Brake | 150                                |                  |                      |
|   |   | Converter       | 150                                |                  |                      |
| Case temperature  | $T_c$   |                 | 125                                |                  |                      |
| Storage temperature   | $T_{stg}$   |                 | -40 to +125                        |                  |                      |
| Isolation voltage   | between terminal and copper base (*1)<br>between thermistor and others (*2) | $V_{iso}$       | AC : 1min.                         | 2500             | VAC                  |
| Screw torque  | Mounting (*3)   | -               | M4                                 | 1.7              | Nm                   |

Note \*1: All terminals should be connected together during the test.

Note \*2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note \*3: Recommendable value : 1.3-1.7 Nm (M4)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

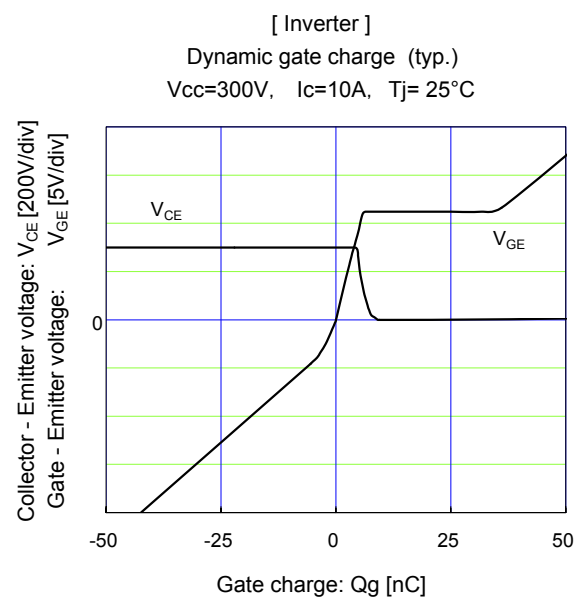
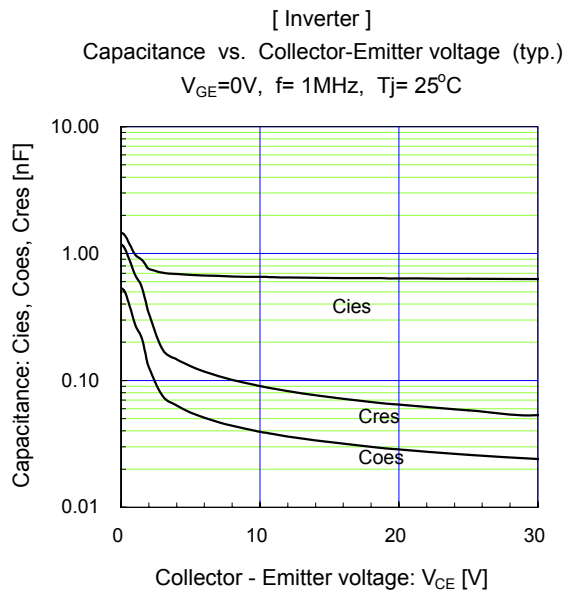
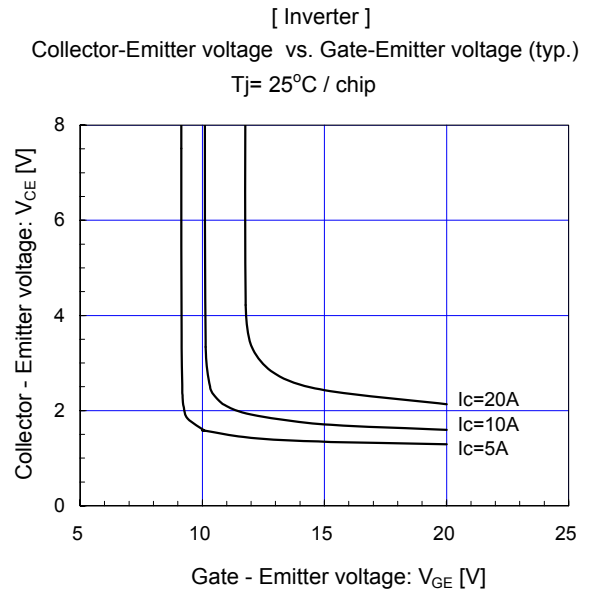
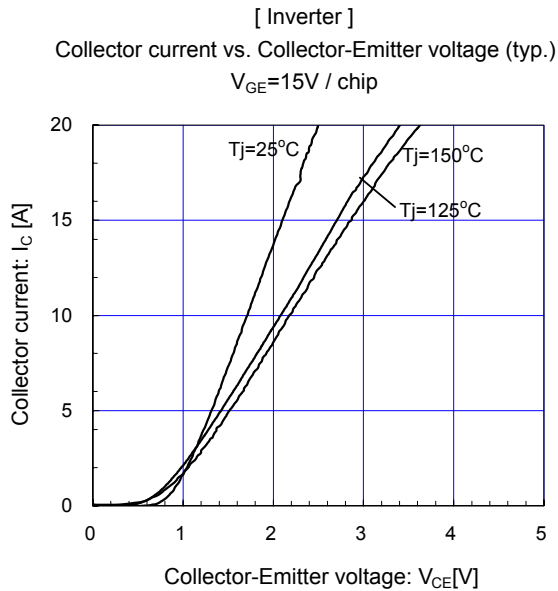
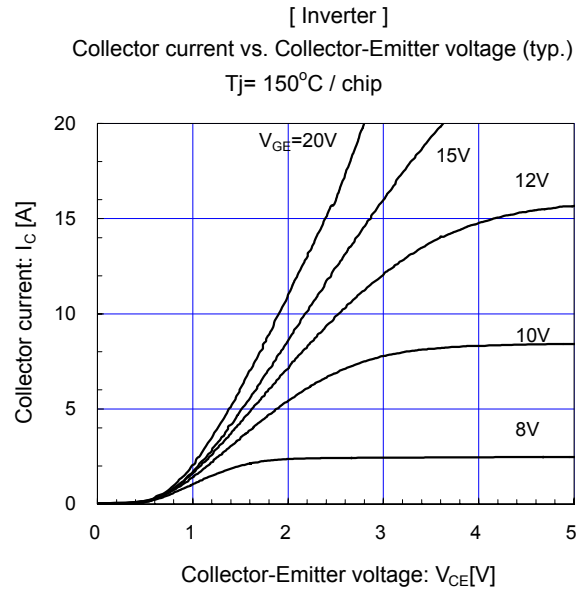
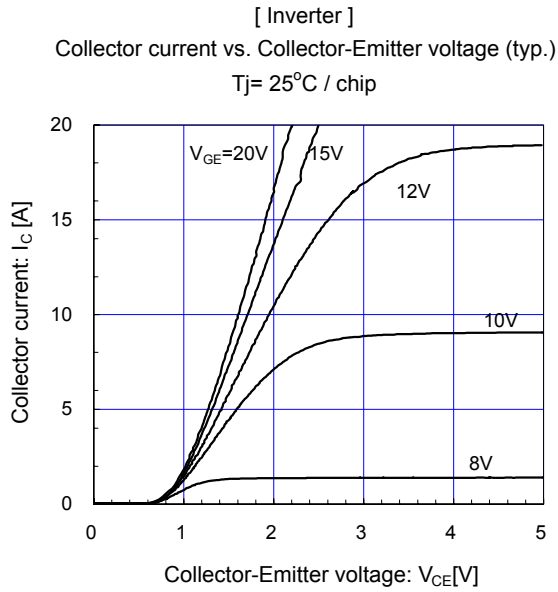
| Items                 | Symbols                              | Conditions                  | Characteristics                        |          |      | Units |      |   |
|-----------------------|--------------------------------------|-----------------------------|--|----------|------|-------|------|---|
|                       |                                      |                             | min.                                   | typ.     | max. |       |      |   |
| Inverter              | Zero gate voltage collector current  | $I_{CES}$                   | $V_{GE} = 0V, V_{CE} = 600V$           | -        | -    | 1.0   | mA   |   |
|                       | Gate-Emitter leakage current         | $I_{GES}$                   | $V_{CE} = 0V, V_{GE} = \pm 20V$        | -        | -    | 200   | nA   |   |
|                       | Gate-Emitter threshold voltage       | $V_{GE(th)}$                | $V_{CE} = 20V, I_c = 10mA$             | 6.2      | 6.7  | 7.2   | V    |   |
|                       | Collector-Emitter saturation voltage | $V_{CE(sat)}$<br>(terminal) | $V_{GE} = 15V$<br>$I_c = 10A$          | Tj=25°C  | -    | 1.85  | 2.25 | V |
|                       |                                      |                             |  | Tj=125°C | -    | 2.25  | -    |   |
|                       |                                      |                             |  | Tj=150°C | -    | 2.35  | -    |   |
|                       |                                      | $V_{CE(sat)}$<br>(chip)     | $V_{GE} = 15V$<br>$I_c = 10A$          | Tj=25°C  | -    | 1.70  | 2.10 |   |
|                       |                                      |                             |  | Tj=125°C | -    | 2.10  | -    |   |
|                       | Tj=150°C                             | -                           | 2.20                                   | -        |      |       |      |   |
|                       | Internal gate resistance             | $R_{g(int)}$                | -                                      | -        | 0    | -     | Ω    |   |
|                       | Input capacitance                    | $C_{ies}$                   | $V_{CE} = 10V, V_{GE} = 0V, f = 1MHz$  | -        | 0.7  | -     | nF   |   |
|                       | Turn-on time                         | $t_{on}$                    | $V_{CC} = 300V$<br>$I_c = 10A$         | -        | 0.08 | 1.20  | μs   |   |
|                       |                                      | $t_r$                       |  | -        | 0.06 | 0.60  |      |   |
|                       |                                      | $t_r(i)$                    |  | -        | 0.02 | -     |      |   |
|                       | Turn-off time                        | $t_{off}$                   | $V_{GE} = +15 / -15V$<br>$R_G = 27Ω$   | -        | 0.14 | 1.20  | μs   |   |
| $t_f$                 |                                      | -                           |  | 0.02     | 0.45 |       |      |   |
| Forward on voltage    | $V_F$<br>(terminal)                  | $I_F = 10A$                 | Tj=25°C                                | -        | 1.90 | 2.30  | V    |   |
|                       |                                      |                             | Tj=125°C                               | -        | 1.85 | -     |      |   |
|                       |                                      |                             | Tj=150°C                               | -        | 1.85 | -     |      |   |
|                       | $V_F$<br>(chip)                      | $I_F = 10A$                 | Tj=25°C                                | -        | 1.75 | 2.15  |      |   |
|                       |                                      |                             | Tj=125°C                               | -        | 1.70 | -     |      |   |
| Tj=150°C              | -                                    | 1.70                        | -                                      |          |      |       |      |   |
| Reverse recovery time | $t_{rr}$                             | $I_F = 10A$                 | -                                      | -        | 0.35 | μs    |      |   |
| Brake                 | Zero gate voltage collector current  | $I_{CES}$                   | $V_{GE} = 0V$<br>$V_{CE} = 600V$       | -        | -    | 1.0   | mA   |   |
|                       | Gate-Emitter leakage current         | $I_{GES}$                   | $V_{CE} = 0V$<br>$V_{GE} = +20 / -20V$ | -        | -    | 200   | nA   |   |
|                       | Collector-Emitter saturation voltage | $V_{CE(sat)}$<br>(terminal) | $V_{GE} = 15V$<br>$I_c = 10A$          | Tj=25°C  | -    | 1.85  | 2.25 | V |
|                       |                                      |                             |  | Tj=125°C | -    | 2.25  | -    |   |
|                       |                                      |                             |  | Tj=150°C | -    | 2.35  | -    |   |
|                       |                                      | $V_{CE(sat)}$<br>(chip)     | $V_{GE} = 15V$<br>$I_c = 10A$          | Tj=25°C  | -    | 1.70  | 2.10 |   |
|                       |                                      |                             |  | Tj=125°C | -    | 2.10  | -    |   |
|                       | Tj=150°C                             | -                           | 2.20                                   | -        |      |       |      |   |
|                       | Internal gate resistance             | $R_{g(int)}$                | -                                      | -        | 0    | -     | Ω    |   |
|                       | Turn-on time                         | $t_{on}$                    | $V_{CE} = 300V$<br>$I_c = 10A$         | -        | 0.08 | 1.20  | μs   |   |
|                       |                                      | $t_r$                       |  | -        | 0.06 | 0.60  |      |   |
|                       | Turn-off time                        | $t_{off}$                   | $V_{GE} = +15 / -15V$<br>$R_G = 27Ω$   | -        | 0.14 | 1.20  | μs   |   |
|                       |                                      | $t_f$                       |  | -        | 0.02 | 0.45  |      |   |
|                       | Reverse current                      | $I_{RRM}$                   | $V_R = 600V$                           | -        | -    | 1.00  | mA   |   |
|                       | Converter                            | Forward on voltage          | $I_F = 10A$                            | terminal | -    | 1.10  | 1.55 | V |
| chip                  |                                      |                             |  | -        | 0.95 | -     |      |   |
| Reverse current       | $I_{RRM}$                            | $V_R = 800V$                | -                                      | -        | 1.00 | mA    |      |   |
| Thermistor            | Resistance                           | T = 25°C                    | -                                      | 5000     | -    | Ω     |      |   |
|                       |                                      | T = 100°C                   | 465                                    | 495      | 520  |       |      |   |
| B value               | B                                    | T = 25 / 50°C               | 3305                                   | 3375     | 3450 | K     |      |   |

● Thermal resistance characteristics

| Items                                     | Symbols       | Conditions            | Characteristics |      |      | Units |
|---|---------------|-----------------------|-----------------|------|------|-------|
|   |               |                       | min.            | typ. | max. |       |
| Thermal resistance (1device)              | $R_{th(j-c)}$ | Inverter IGBT         | -               | -    | 2.15 | °C/W  |
|   |               | Inverter FWD          | -               | -    | 2.96 |       |
|   |               | Brake IGBT            | -               | -    | 2.15 |       |
|   |               | Converter Diode       | -               | -    | 1.35 |       |
| Contact thermal resistance (1device) (*4) | $R_{th(c-f)}$ | with Thermal Compound | -               | 0.05 | -    |       |

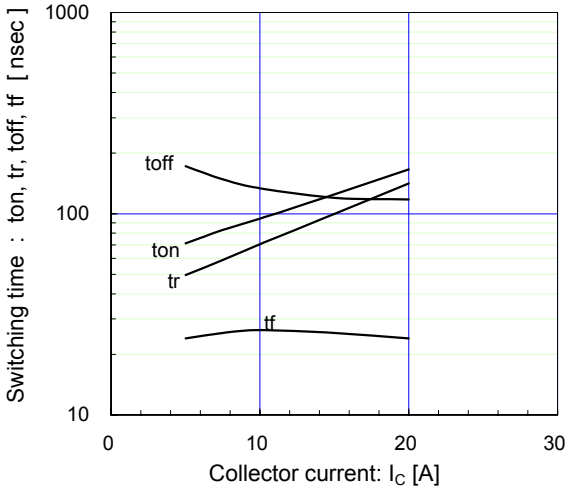
Note \*4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)



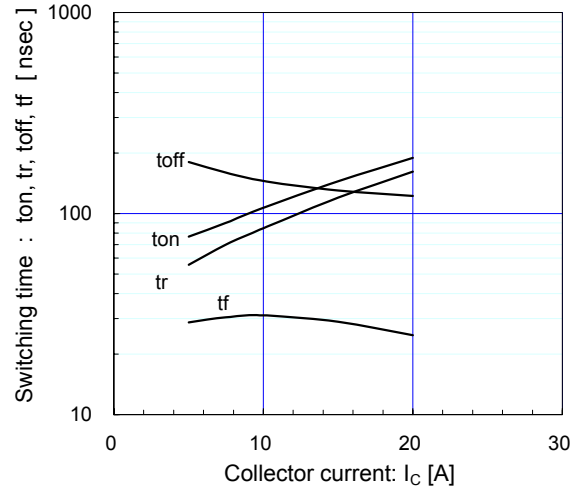
[ Inverter ]

Switching time vs. Collector current (typ.)  
 $V_{CC}=300V, V_{GE}=\pm 15V, R_G=27\Omega, T_j=125^\circ C$



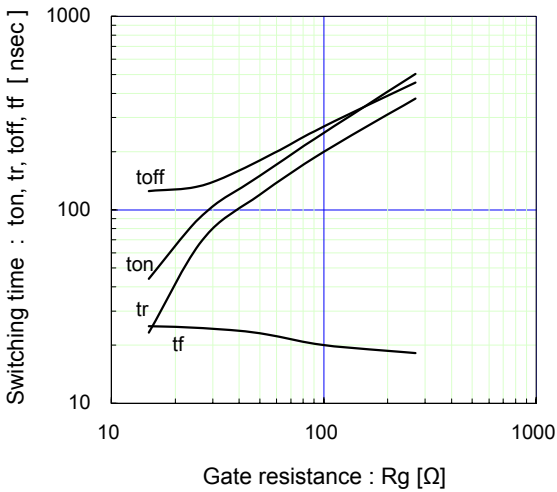
[ Inverter ]

Switching time vs. Collector current (typ.)  
 $V_{CC}=300V, V_{GE}=\pm 15V, R_G=27\Omega, T_j=150^\circ C$



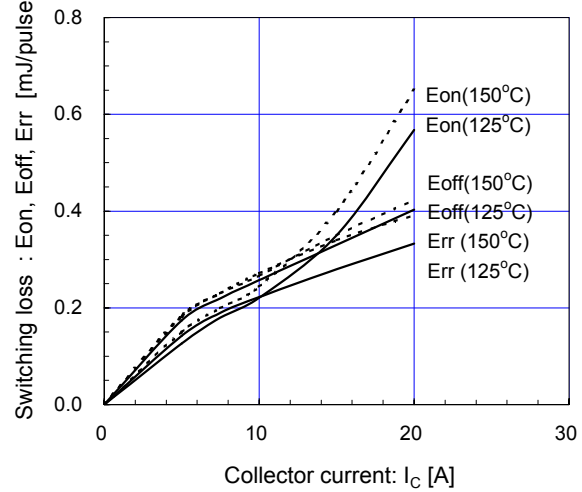
[ Inverter ]

Switching time vs. gate resistance (typ.)  
 $V_{CC}=300V, I_C=10A, V_{GE}=\pm 15V, T_j=125^\circ C$



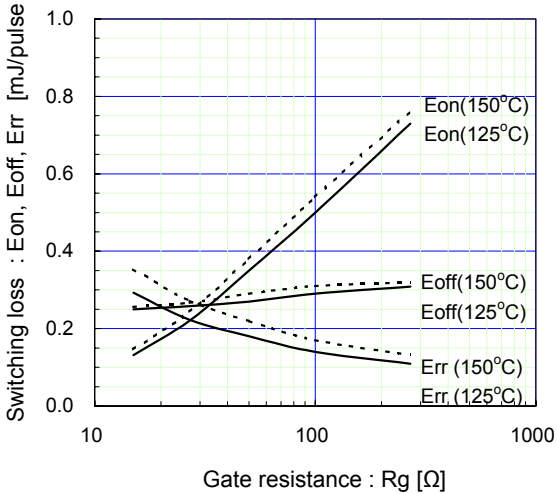
[ Inverter ]

Switching loss vs. Collector current (typ.)  
 $V_{CC}=300V, V_{GE}=\pm 15V, R_G=27\Omega$



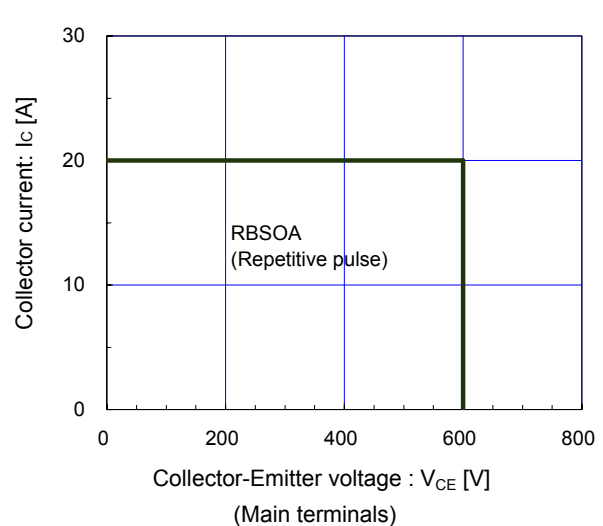
[ Inverter ]

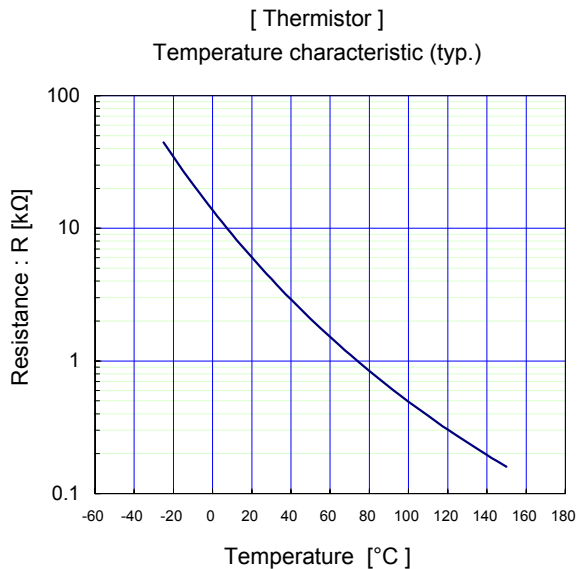
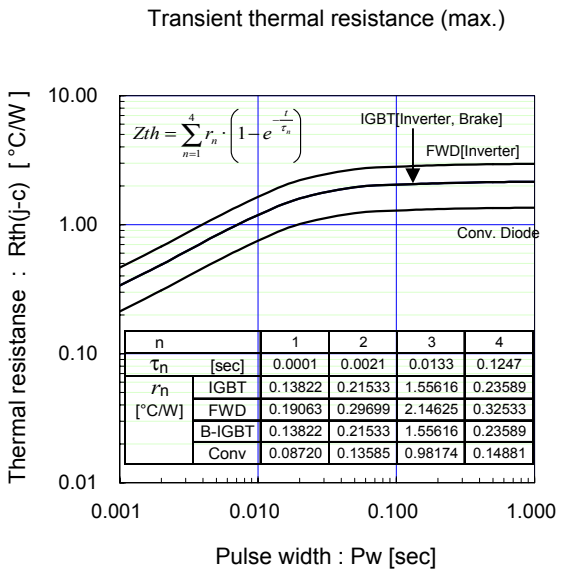
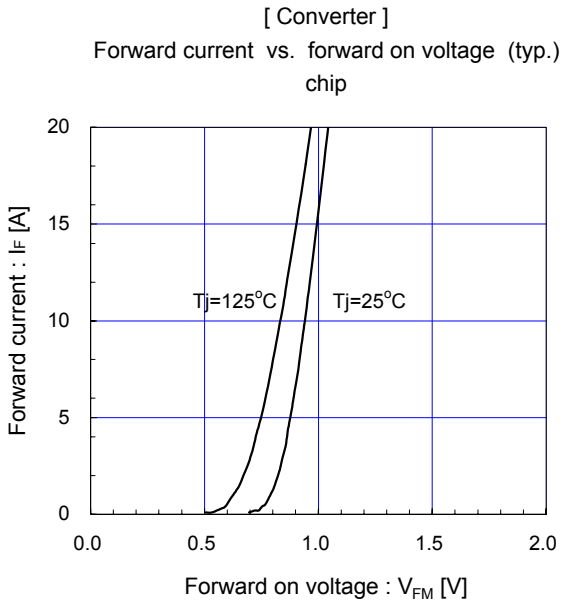
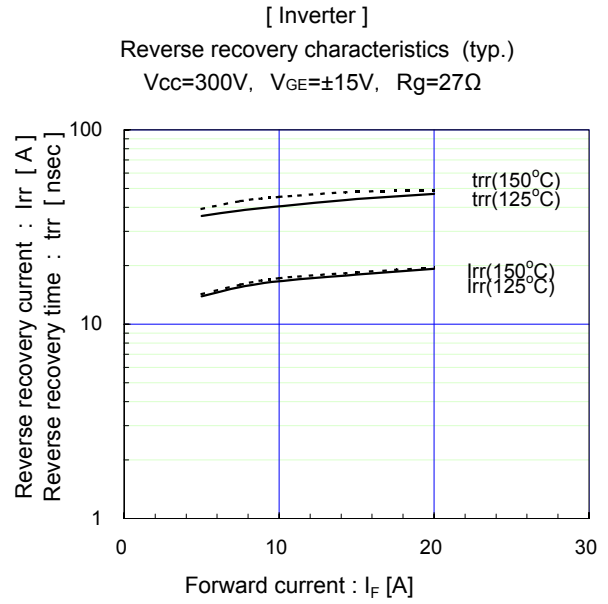
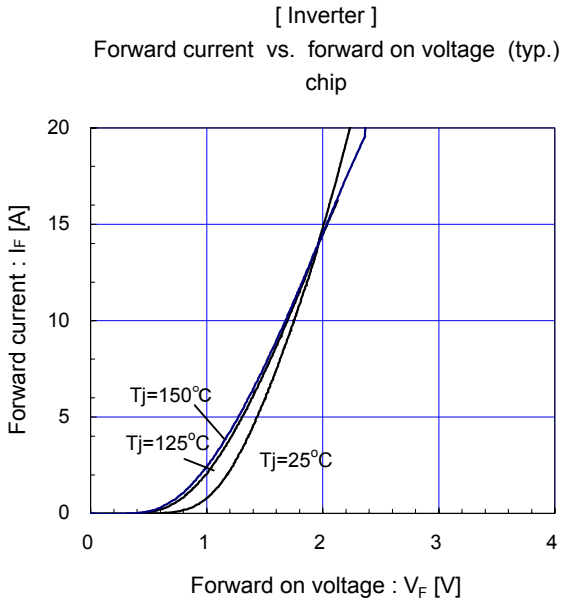
Switching loss vs. gate resistance (typ.)  
 $V_{CC}=300V, I_C=10A, V_{GE}=\pm 15V$

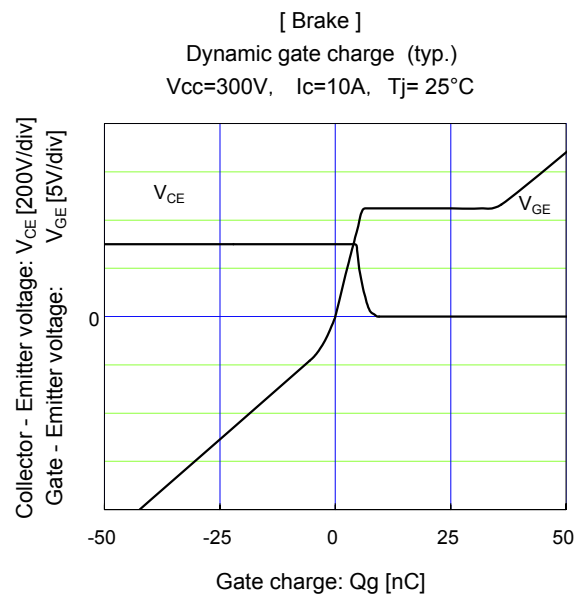
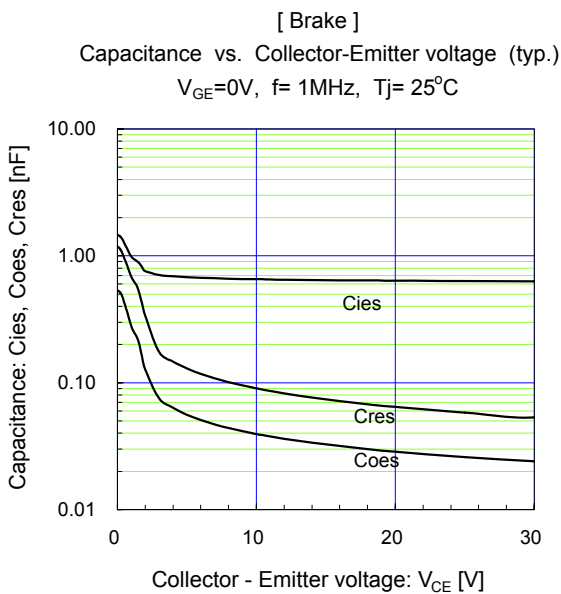
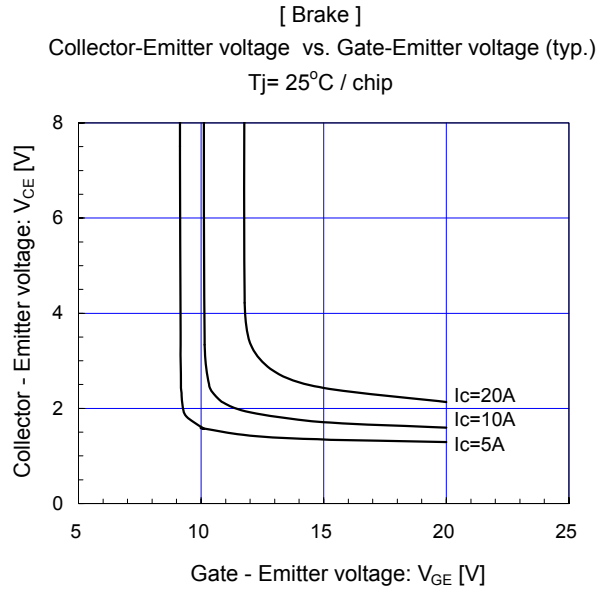
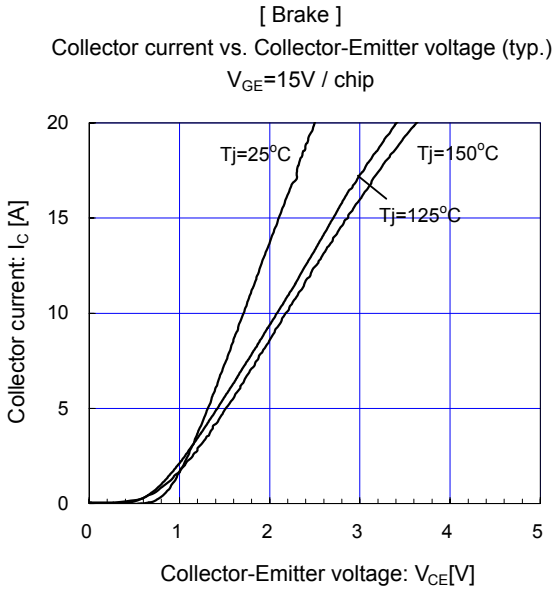
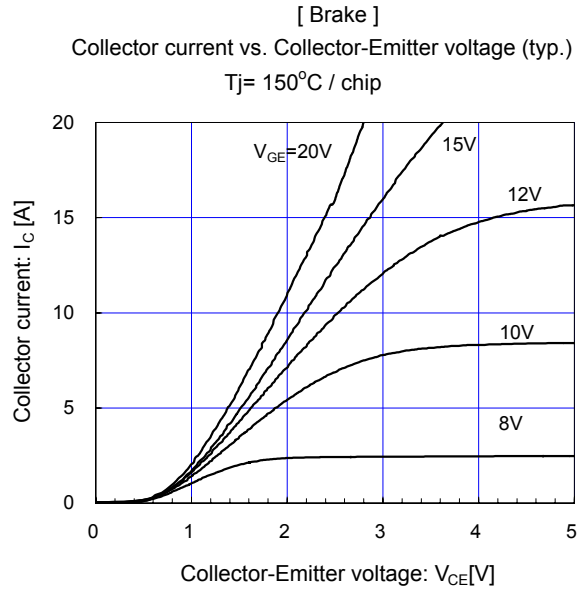
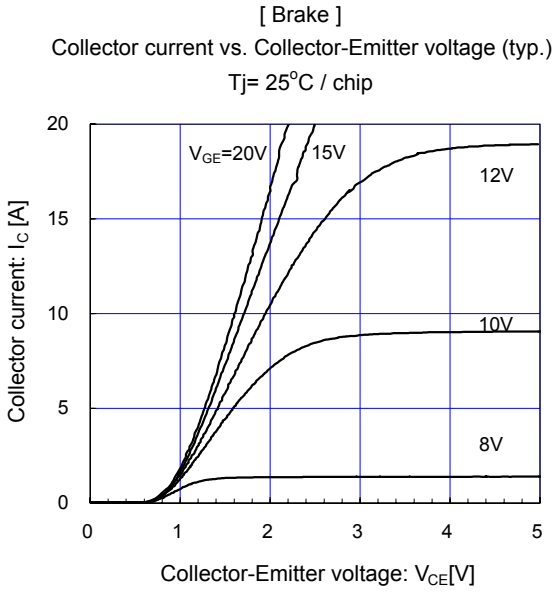


[ Inverter ]

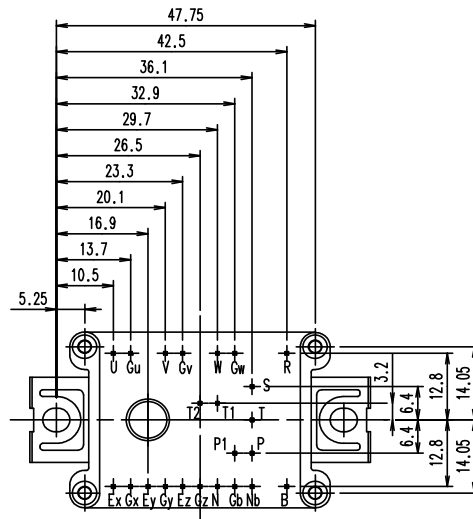
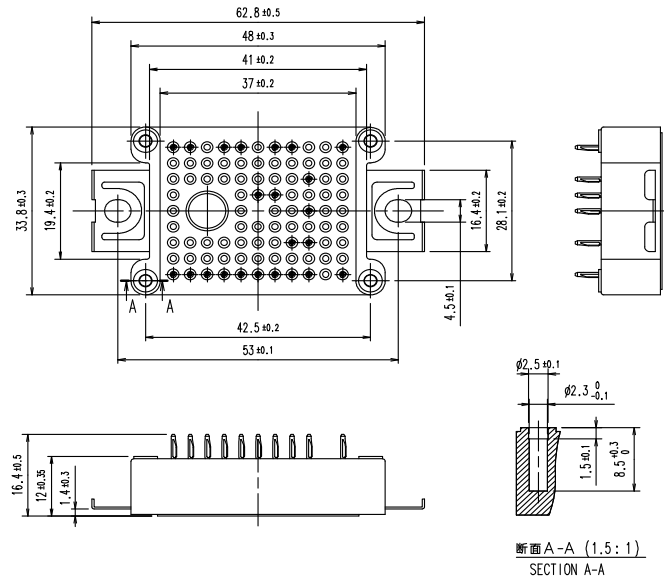
Reverse bias safe operating area (max.)  
 $+V_{GE}=15V, -V_{GE} \leq 15V, R_G \geq 27\Omega, T_j=150^\circ C$







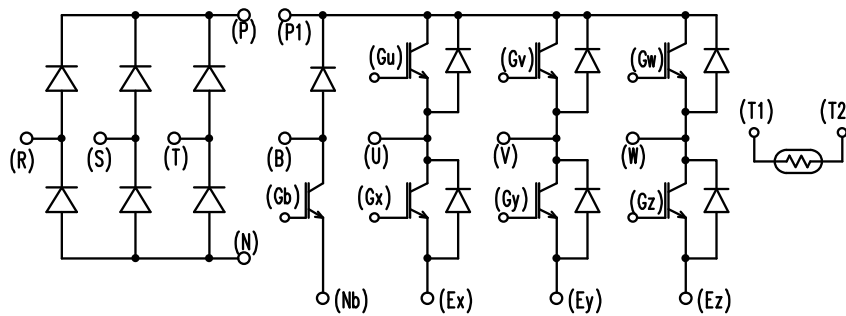
■ Outline drawing (Unit : mm)



Weight: 25g(typ.)

■ Equivalent circuit

[ Converter ]    [ Brake ]    [ Inverter ]    [ Thermistor ]



## WARNING

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|                 |                         |   |                          |
|-----------------|-------------------------|---|--------------------------|
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| • Machine tools | • Audiovisual equipment | • Electrical home appliances                  | • Personal equipment     |
|                 |                         |   | • Industrial robots etc. |
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|   |   |
|---|---|
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| • Traffic-signal control equipment  | • Gas leakage detectors with an auto-shut-off feature |
| • Emergency equipment for responding to disasters and anti-burglary devices | • Safety devices                                      |
| • Medical equipment   |   |
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|                                |                        |                             |
|--------------------------------|------------------------|-----------------------------|
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| • Submarine repeater equipment |                        |                             |
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